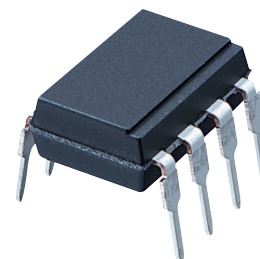


PC942J00000F Series

High Power, Gate Drive type
DIP 8 pin *OPIC Photocoupler



■ Description

PC942J00000F Series contains an IRED optically coupled to an OPIC chip.

It is packaged in a 8 pin DIP, available in SMT gullwing lead form option.

Input-output isolation voltage(rms) is 5.0kV, High speed response (t_{PHL}, t_{PLH} : MAX. 5 μ s) and CMR is MIN. 10kV/ μ s.

■ Features

1. 8 pin DIP package
2. Double transfer mold package
(Ideal for Flow Soldering)
3. Built-in base amplifier for inverter drive
4. High power (I_{O1} : MAX. 0.5A (DC))
(I_{O2P} : MAX. 2.0A (pulse))
5. High noise immunity due to high instantaneous common mode rejection voltage
(CM_H : MIN. -10 kV/ μ s, CM_L : MIN. 10 kV/ μ s)
6. High speed response (t_{PHL}, t_{PLH} : MAX. 5 μ s)
7. High isolation voltage between input and output
($V_{iso(rms)}$: 5.0 kV)
8. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC942**)
2. Package resin : UL flammability grade (94V-0)

■ Applications

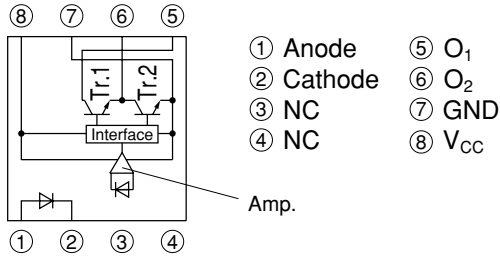
1. Inverter controlled air conditioners
2. Small capacity general purpose inverters

* "OPIC"(Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

Notice The content of data sheet is subject to change without prior notice.

In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

■ Internal Connection Diagram

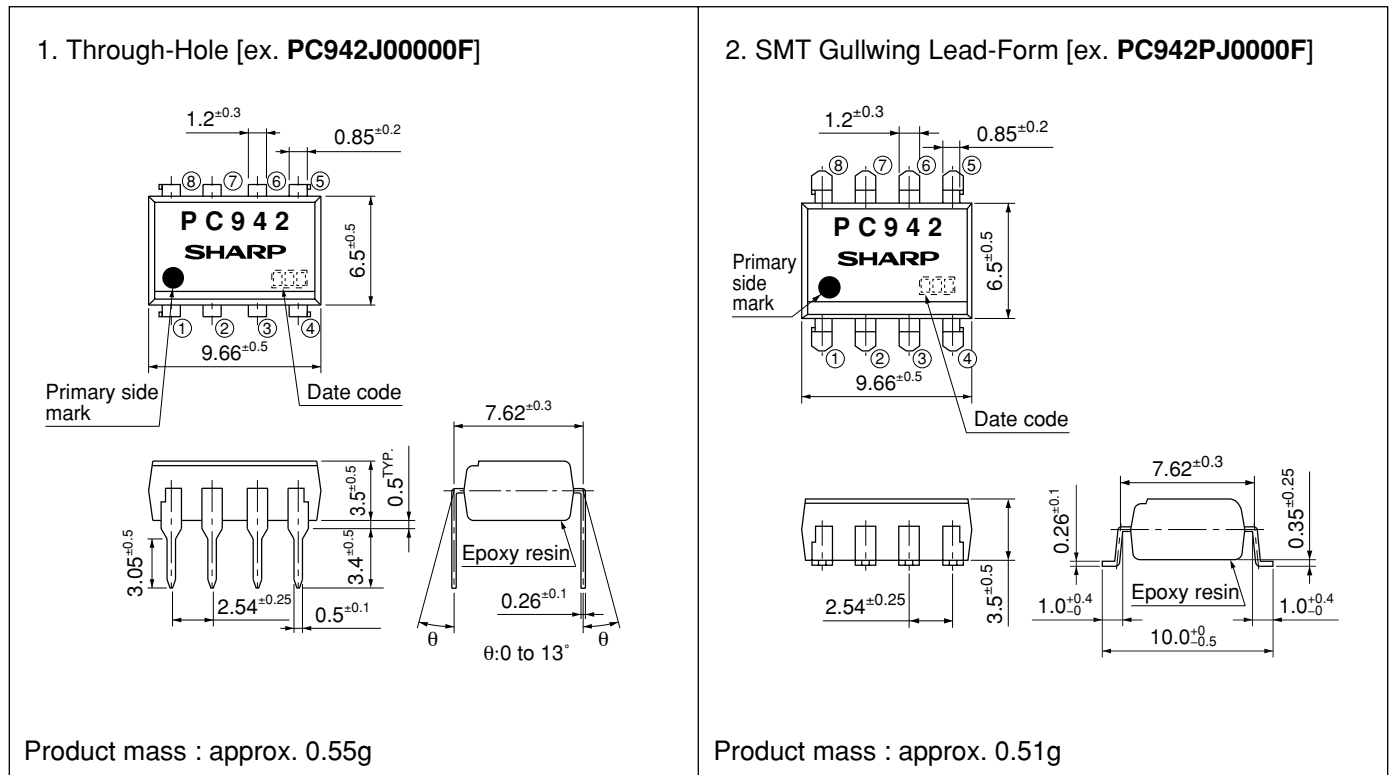


■ Truth table

Input	O ₂ Terminal output	Tr. 1	Tr. 2
ON	High level	ON	OFF
OFF	Low level	OFF	ON

■ Outline Dimensions

(Unit : mm)



Date code (3 digit)

1st digit				2nd digit		3rd digit	
Year of production				Month of production		Week of production	
A.D.	Mark	A.D	Mark	Month	Mark	Week	Mark
1990	A	2002	P	January	1	1st	1
1991	B	2003	R	February	2	2nd	2
1992	C	2004	S	March	3	3rd	3
1993	D	2005	T	April	4	4th	4
1994	E	2006	U	May	5	5.6th	5
1995	F	2007	V	June	6		
1996	H	2008	W	July	7		
1997	J	2009	X	August	8		
1998	K	2010	A	September	9		
1999	L	2011	B	October	O		
2000	M	2012	C	November	N		
2001	N	∴	∴	December	D		

repeats in a 20 year cycle

Country of origin

Japan

Rank mark

There is no rank mark indicator.

■ Absolute Maximum Ratings

(Unless otherwise specified $T_a=T_{opr}$)

	Parameter	Symbol	Rating	Unit
Input	*1 Forward current	I_F	25	mA
	*2 Reverse voltage	V_R	6	V
Output	Supply voltage	V_{CC}	18	V
	O_1 output current	I_{O1}	0.5	A
	*3 O_1 Peak output current	I_{O1P}	1.0	A
	O_2 output current	I_{O2}	0.6	A
	*3 O_2 Peak output current	I_{O2P}	2.0	A
	O_1 output voltage	V_{O1}	18	V
	*4 Power dissipation	P_O	500	mW
*5 Total power dissipation		P_{tot}	550	mW
*6 Isolation voltage		$V_{iso} (rms)$	5.0	kV
Operating temperature		T_{opr}	-20 to +80	°C
Storage temperature		T_{stg}	-55 to +125	°C
*7 Soldering temperature		T_{sol}	260	°C

*1 The derating factors of a absolute maximum ratings due to ambient temperature are shown in Fig.8

*2 $T_a=25^\circ C$ *3 Pulse width $\leq 5\mu s$, Duty ratio : 0.01

*4.5 The derating factors of a absolute maximum ratings due to ambient temperature are shown in Fig.8

*6 AC for 1minute, 40 to 60 %RH, $T_a=25^\circ C$, $f=60Hz$ *7 For 10s

■ Electro-optical Characteristics

(Unless otherwise specified $T_a=T_{opr}$)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V_{F1}	$T_a=25^\circ C, I_F=5mA$	-	1.1	1.4	V	
		V_{F2}	$T_a=25^\circ C, I_F=0.2mA$	0.6	0.9	-	V	
	Reverse current	I_R	$T_a=25^\circ C, V_R=3V$	-	-	10	μA	
	Terminal capacitance	C_t	$T_a=25^\circ C, V=0, f=1kHz$	-	30	250	pF	
Output	Supply voltage	V_{CC}	-	5.4	-	13	V	
	O_1 Low level output voltage	V_{O1L}	$V_{CC}=6V, I_{O1}=0.4A, R_{L2}=10\Omega, I_F=5mA$	-	0.2	0.4	V	
	O_2 High level output voltage	V_{O2H}	$V_{CC}=6V, I_{O2}=-0.4A, I_F=5mA$	4.5	5.0	-	V	
	O_2 Low level output voltage	V_{O2L}	$V_{CC}=6V, I_{O2}=0.5A, I_F=0$	-	0.2	0.4	V	
	O_1 leak current	I_{O1L}	$V_{CC}=13V, I_F=0$	-	-	200	μA	
	O_2 leak current	I_{O2L}	$V_{CC}=13V, I_F=5mA$	-	-	200	μA	
	High level supply current	I_{CCH}	$T_a=25^\circ C, V=6V, I_F=5mA$	-	9	13	mA	
			$V_{CC}=6V, I_F=5mA$	-	-	17	mA	
	Low level supply current	I_{CCL}	$T_a=25^\circ C, V_{CC}=6V, I_F=0$	-	11	15	mA	
			$V_{CC}=6V, I_F=0$	-	-	20	mA	
*8 "Low→High" input threshold current	I_{FLH}	$T_a=25^\circ C, V_{CC}=6V, R_{L1}=5\Omega, R_{L2}=10\Omega$	0.3	1.5	3.0	mA		
		$V_{CC}=6V, R_{L1}=5\Omega, R_{L2}=10\Omega$	0.2	-	5.0	mA		
Transfer characteristics	Isolation resistance	R_{ISO}	$T_a=25^\circ C, DC500V, 40 to 60\%RH$	5×10^{10}	10^{11}	-	Ω	
	Response time	"Low→High" propagation delay time	t_{PLH}	$T_a=25^\circ C, V_{CC}=6V, I_F=5mA$ $R_{L1}=5\Omega, R_{L2}=10\Omega$	-	2	5	μs
		"High→Low" propagation delay time	t_{PHL}		-	2	5	μs
		Rise time	t_r		-	0.2	1	μs
		Fall time	t_f		-	0.1	1	μs
	Instantaneous common mode rejection voltage (High level output)	CM_H	$T_a=25^\circ C, V_{CM}=600V(peak)$ $I_F=5mA, R_{L1}=470\Omega$ $R_{L2}=1k\Omega, \Delta V_{O2H}=0.5V(MAX)$	-10	-	-	kV/ μs	
Instantaneous common mode rejection voltage (Low level output)	CM_L	$T_a=25^\circ C, V_{CM}=600V(peak)$ $I_F=0, R_{L1}=470\Omega$ $R_{L2}=1k\Omega, \Delta V_{O2L}=0.5V(MAX)$	10	-	-	kV/ μs		

*8 I_{FLH} represents forward current when output goes from "Low" to "High"

■ Model Line-up

Lead Form	Through-Hole	SMT Gullwing
Package	Sleeve	Taping
	50pcs/sleeve	1 000pcs/reel
Model No.	PC942J00000F	PC942PJ0000F

Please contact a local SHARP sales representative to inquire about production status.

Fig.1 Test Circuit for O₁ Low Level Output Voltage

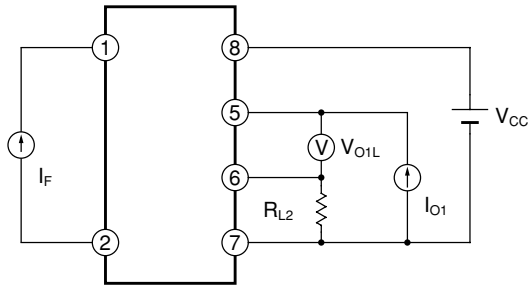


Fig.2 Test Circuit for O₂ High Level Output Voltage

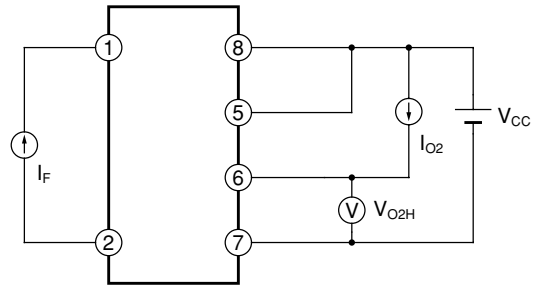


Fig.3 Test Circuit for O₁ Leak Current

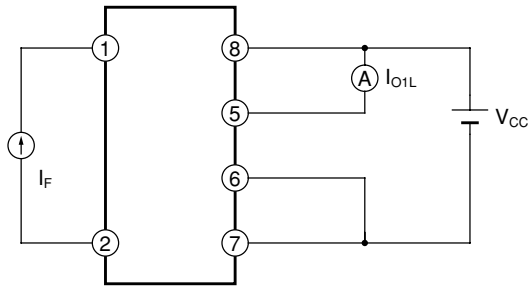


Fig.4 Test Circuit for O₂ Leak Current

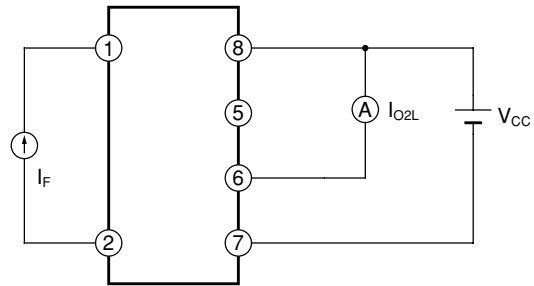


Fig.5 Test Circuit for "Low→High" Input Threshold Current

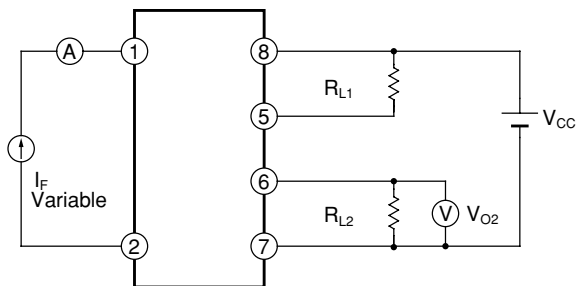


Fig.6 Test Circuit for Response Time

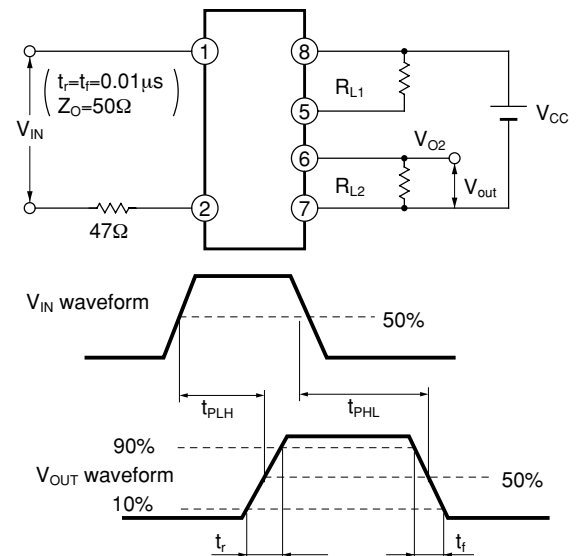


Fig.7 Test Circuit for Instantaneous Common Mode Rejection Voltage

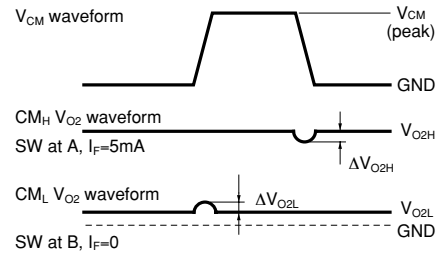
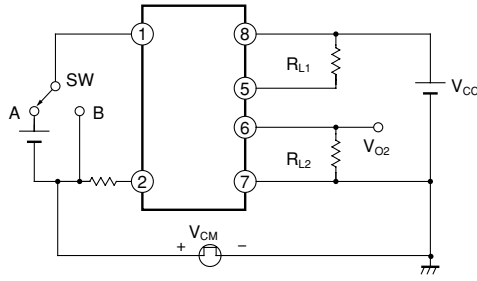


Fig.8 Forward Current vs. Ambient Temperature

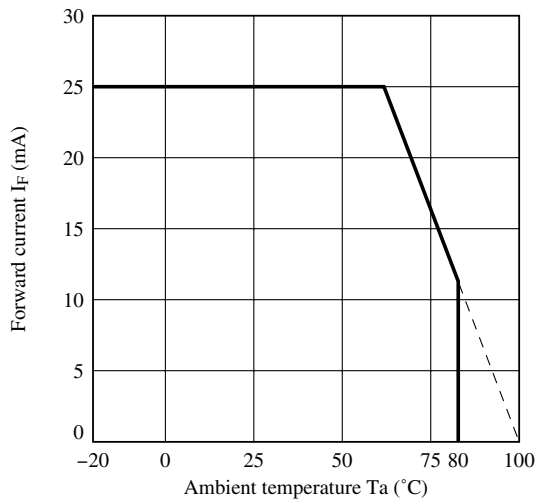


Fig.9 Power Dissipation vs. Ambient Temperature

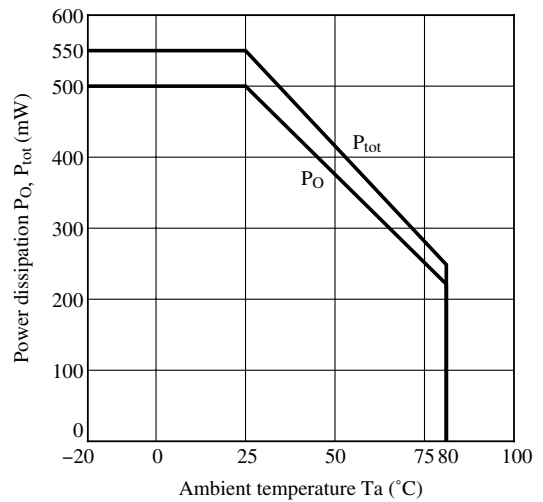


Fig.10 Forward Current vs. Forward Voltage

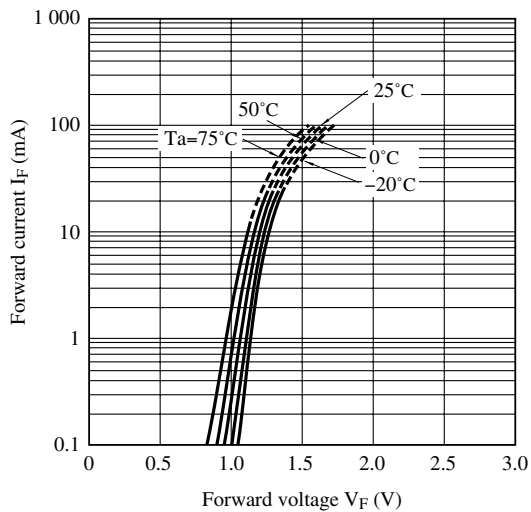


Fig.11 "Low→High" Relative Input Threshold Current vs. Supply Voltage

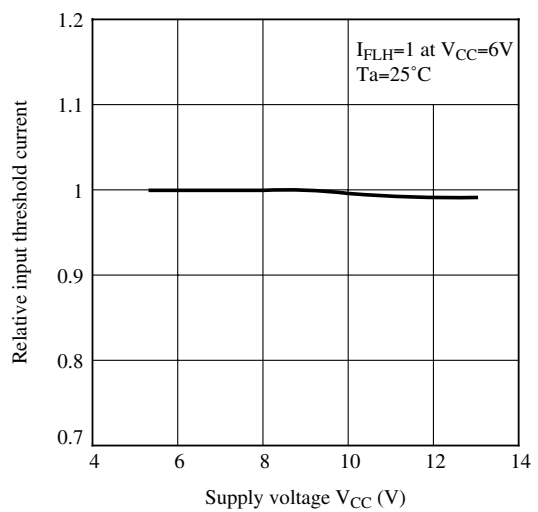


Fig.12 "Low→High" Relative Input Threshold Current vs. Ambient Temperature

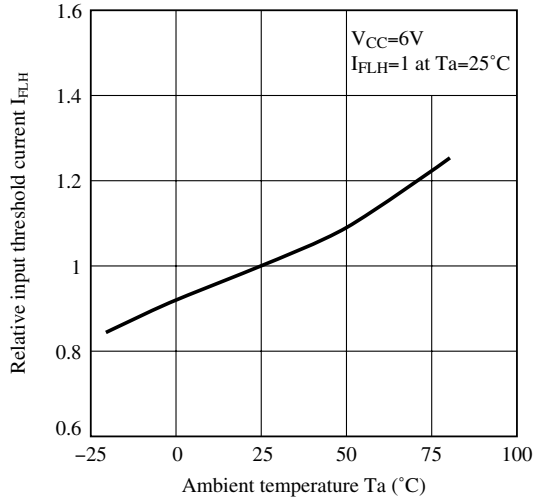


Fig.13 O₁ Low Level Output Voltage vs. O₁ Output Current

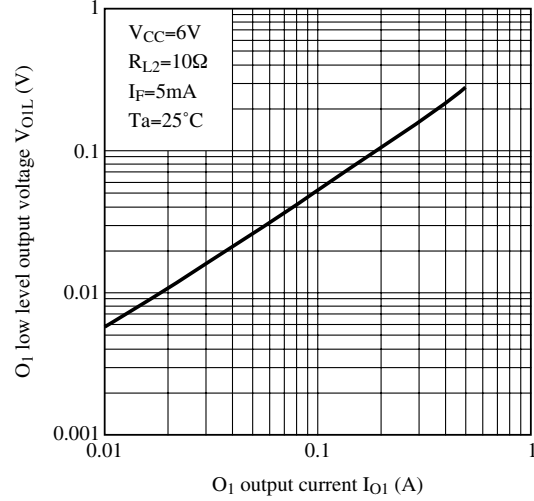


Fig.14 O₁ Low Level Output Voltage vs. Ambient Temperature

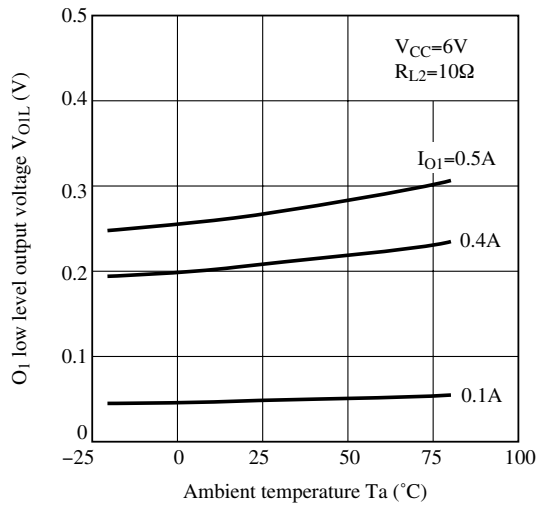


Fig.15 O₂ High Level Output Voltage vs. O₂ Output Current

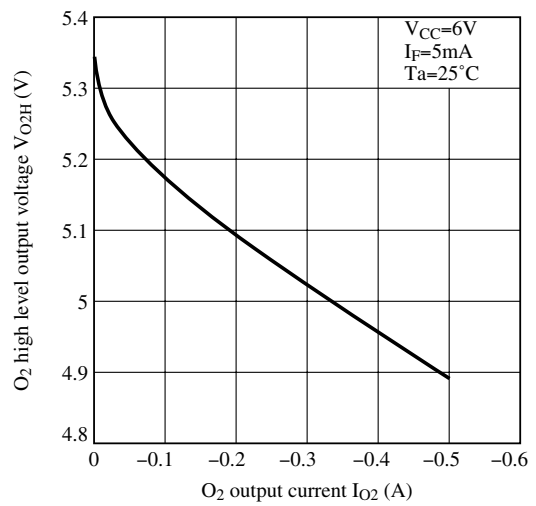


Fig.16 O₂ High Level Output Voltage vs. Ambient Temperature

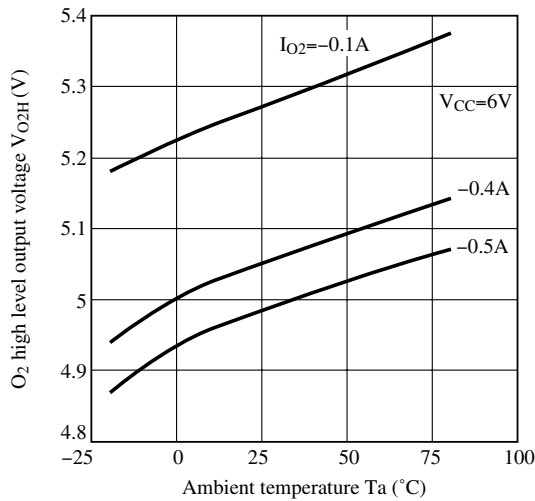


Fig.17 O₂ Low Level Output Voltage vs. O₂ Output Current

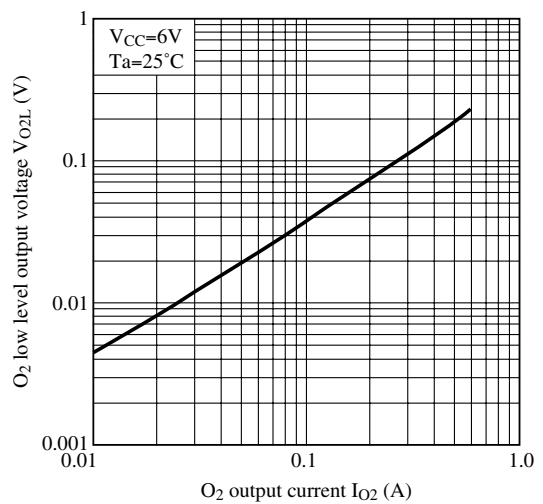


Fig.18 O₂ Low Level Output Voltage vs. Ambient Temperature

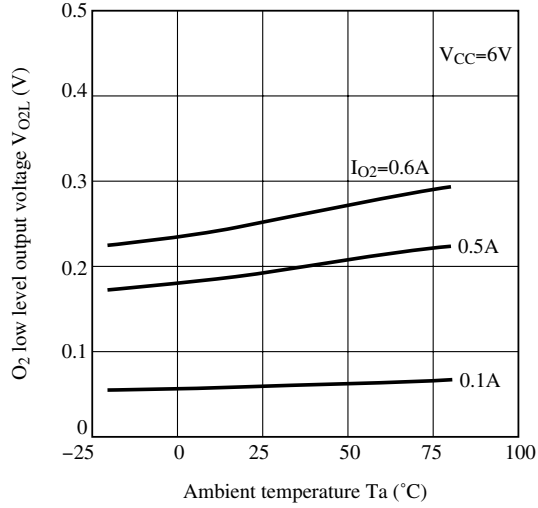


Fig.19 High Level Supply Current vs. Supply Voltage

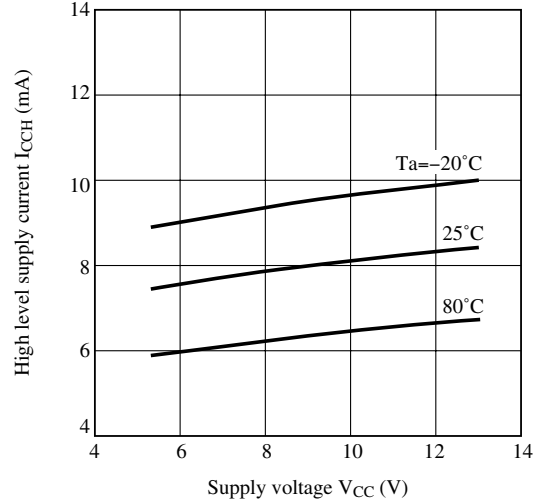


Fig.20 Low Level Supply Current vs. Supply Voltage

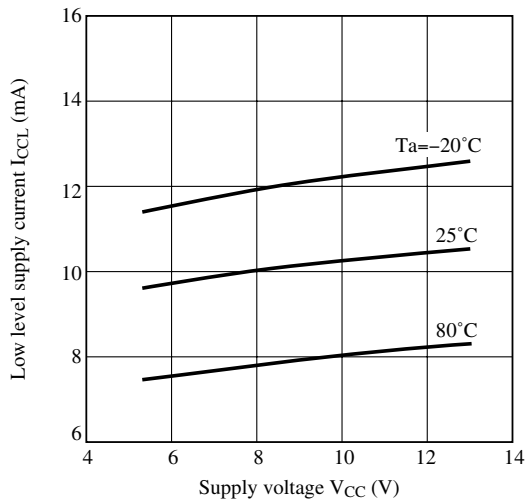


Fig.21 Propagation Delay Time vs. Forward Current

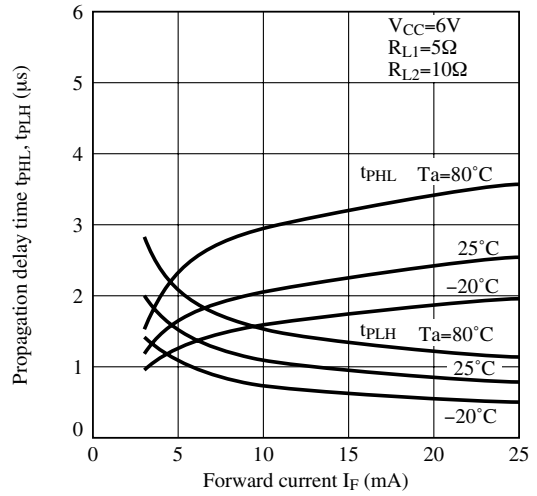


Fig.22 Propagation Delay Time vs. Ambient Temperature

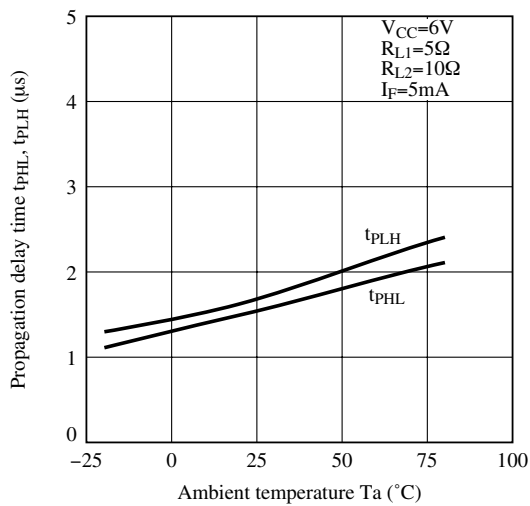


Fig.23 O₂ Peak Output Current vs. O₂ Low Level Output Voltage

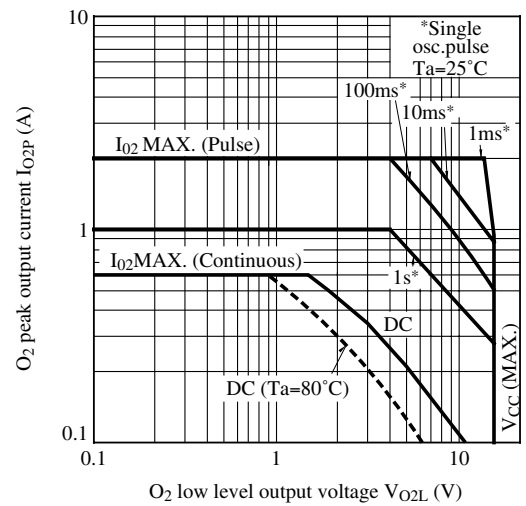
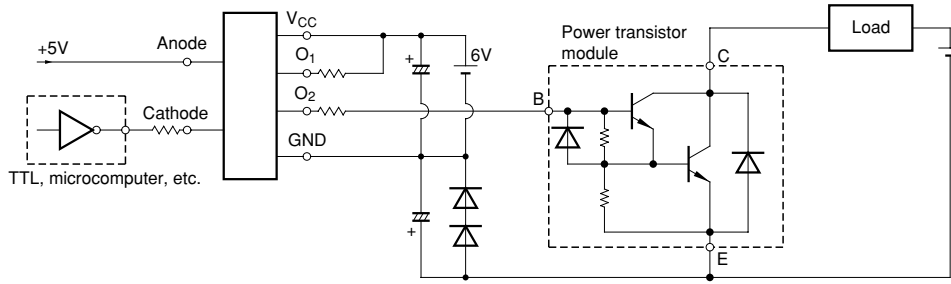


Fig.24 Application Circuit



This application circuit shows the general example of a circuit, and is not a design guarantee for right operation.

Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

■ Design Considerations**● Notes about static electricity**

Transistor of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handling these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

● Design guide

In order to stabilize power supply line, we should certainly recommend to connect a by-pass capacitor of 0.01 μ F or more between V_{CC} and GND near the device.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through IRED or current may change.

If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of IRED.

The detector which is used in this device, has parasitic diode between each pins and GND.

There are cases that miss operation or destruction possibly may be occurred if electric potential of any pin becomes below GND level even for instant.

Therefore it shall be recommended to design the circuit that electric potential of any pin does not become below GND level.

This product is not designed against irradiation and incorporates non-coherent IRED.

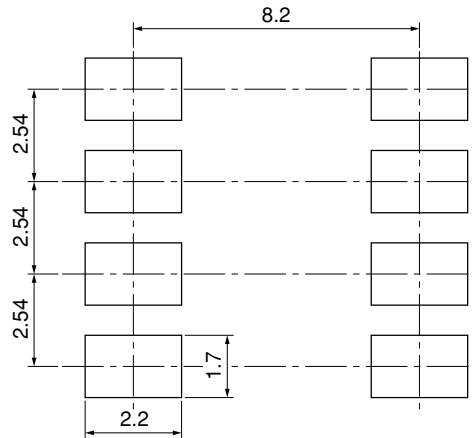
● Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Please decide the input current which become 2 times of MAX. I_{FLH} .

● Recommended Foot Print (reference)



(Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

■ Manufacturing Guidelines

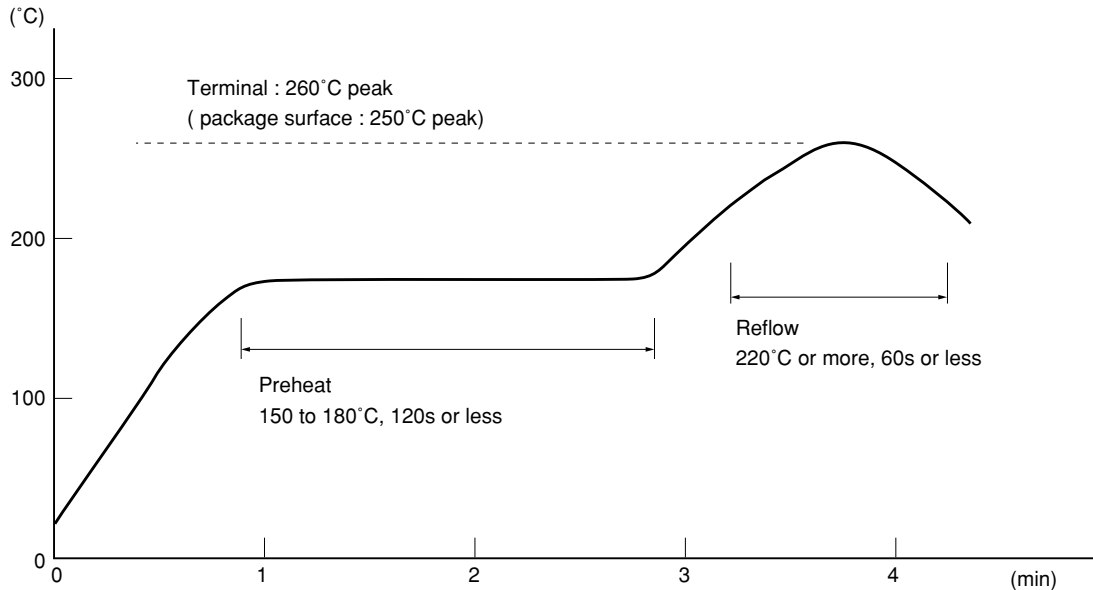
● Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

● Cleaning instructions**Solvent cleaning:**

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

● Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

- Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

■ **Package specification**

● **Sleeve package**

Package materials

Sleeve : HIPS (with anti-static material)

Stopper : Styrene-Elastomer

Package method

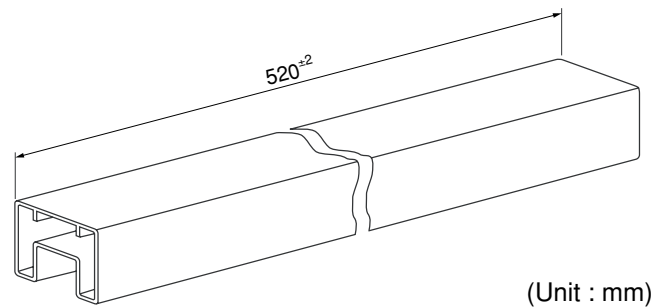
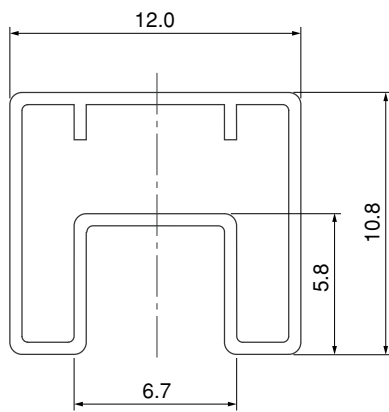
MAX. 50 pcs. of products shall be packaged in a sleeve.

Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its primary side mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions



● **Tape and Reel package**

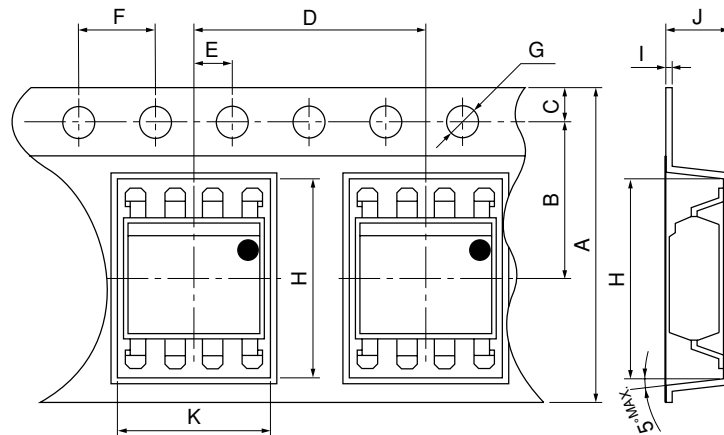
Package materials

Carrier tape : A-PET (with anti-static material)

Cover tape : PET (three layer system)

Reel : PS

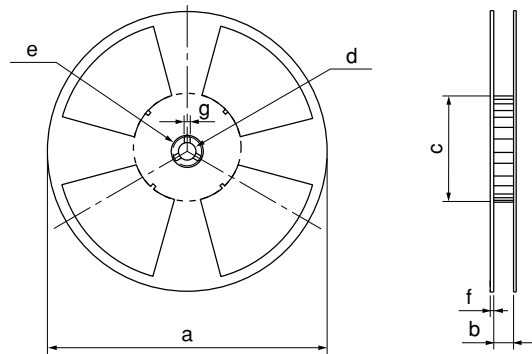
Carrier tape structure and Dimensions



Dimensions List (Unit : mm)

A	B	C	D	E	F	G
16.0±0.3	7.5±0.1	1.75±0.1	12.0±0.1	2.0±0.1	4.0±0.1	φ1.5±0.1
H	I	J	K			
10.4±0.1	0.4±0.05	4.2±0.1	10.2±0.1			

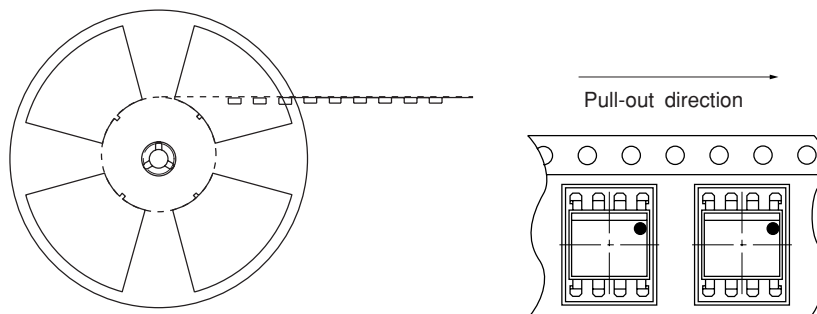
Reel structure and Dimensions



Dimensions List (Unit : mm)

a	b	c	d
330	17.5±1.5	100±1.0	13±0.5
e	f	g	
23±1.0	2.0±0.5	2.0±0.5	

Direction of product insertion



[Packing : 1 000pcs/reel]

■ Important Notices

· The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.

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· Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:

(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- Personal computers
- Office automation equipment
- Telecommunication equipment [terminal]
- Test and measurement equipment
- Industrial control
- Audio visual equipment
- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- Traffic signals
- Gas leakage sensor breakers
- Alarm equipment
- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- Space applications
- Telecommunication equipment [trunk lines]
- Nuclear power control equipment
- Medical and other life support equipment (e.g., scuba).

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